

## TL0375J: 2.0 – 5.0 GHz Ultra Low Noise Amplifier

### 1.0 Features

- Small signal gain @ 3600MHz: 17.5dB
- NF @ 3600MHz: 0.4dB
- P1dB @ 3600MHz: 19.5dBm
- 5V Typical operating voltage
- Operating frequency: 2.0 to 5.0GHz



**Figure 1.1 Device Image**  
(8 Pin 2x2x0.75mm QFN Package)

### 2.0 Applications

- 4G/5G Infrastructure Radios
- Small Cells and Cellular Repeaters
- Phase Array Radar
- SDARS

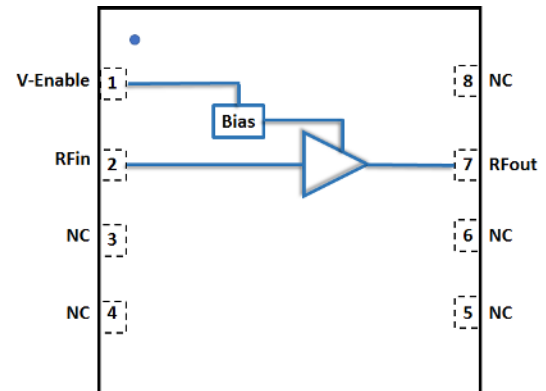


**RoHS/REACH/Halogen Free Compliance**

### 3.0 Description

The TL0375J is a high frequency version of TL0374J which is a broadband, ultra-low Noise Amplifier (LNA). With a simple input and output match, this LNA can be tuned for different frequency bands targeting LTE (small cells and infrastructure), radar and any other applications requiring low noise, high gain, and linearity.

The TL0375J is packaged in a compact, low cost Dual Flat No Lead (DFN) 2x2x0.75mm, 8 pin plastic package.



**Figure 3.1 Function Block Diagram**  
(Top View)

### 4.0 Ordering Information

**Table 4.1 Ordering Information**

Base Part Number	Package Type	Form	Qty	Reel Diameter	Reel Width	Orderable Part Number	
TL0375J	8 Pin 2x2x0.75mm DFN	Tape and Reel	3000	13" (330mm)	18mm	TL0375JMTRPBF	
						Tuned Evaluation Board, 3300 - 3800MHz	TL0375J-EVB-A
						Tuned Evaluation Board, 3700 - 4200MHz	TL0375J-EVB-B
						Tuned Evaluation Board, 4400 - 5000MHz	TL0375J-EVB-C

## 5.0 Pin Description

**Table 5.1 Pin Definition**

Pin Number	Pin Name	Description
3-6, 8	NC	No internal connection, can be connected to ground
1	Venable	Venable along with series resistor, sets the Idq. Venable <0.2V disables the device
2	RF <sub>IN</sub>	RF Input. DC blocking cap required
7	RF <sub>OUT</sub> /V <sub>dd</sub>	RF Output. Vdd supplied through an external choke inductor
Package Base	Paddle/Slug	DC and RF Ground. Also provides thermal relief. Multiple vias are recommended

**Note:** [1] The backside ground slug of the device must be grounded directly to the ground plane through multiple vias to ensure proper operation. Adequate heatsinking required.

## 6.0 Absolute Maximum Rating

**Table 6.1 Absolute Maximum Rating @T<sub>A</sub>=+25°C Unless Otherwise Specified**

Parameter	Symbol	Value	Unit
<b>Electrical Ratings</b>			
Supply voltage, Venable	V <sub>dd</sub>	+6	V
Drain current	I <sub>DQ</sub>	70	mA
RF input power CW	RF <sub>IN</sub>	23	dBm
Storage Temperature Range	T <sub>st</sub>	-55 to +150	°C
Operating Temperature Range	T <sub>op</sub>	-40 to +105	°C
Maximum Junction Temperature	T <sub>J</sub>	170	°C
<b>Thermal Ratings</b>			
Thermal Resistance (junction-to-case) – Bottom side	R <sub>θJC</sub>	15.0	°C/W
Soldering Temperature	T <sub>SOLD</sub>	260	°C
<b>ESD Ratings</b>			
Human Body Model (HBM)	Level 1B	500 to <1000	V
Charged Device Model (CDM)	Level C	≥1000	V
<b>Moisture Rating</b>			
Moisture Sensitivity Level	MSL	1	-

### Attention:

Maximum ratings are absolute ratings. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Exceeding one or a combination of the absolute maximum ratings may cause permanent and irreversible damage to the device and/or to surrounding circuit.

## 7.0 Recommended DC Operating Conditions

**Table 7.1 Recommended Operating Conditions**

Parameter	Symbol	Minimum	Typical	Maximum	Unit
Drain Voltage	$V_{DD}$		+5.0		V
Venable Voltage	$V_{enable}$		+5.0		V
Drain Bias Current	$I_{DQ}$ , Set by external resistor	45	60		mA
Venable Bias Current	$I_{bias}$		3.0		mA
Operating Temperature Range		-40	+25	+105	°C

## 8.0 RF Electrical Specifications for 3300 – 3800MHz, 3700 - 4200MHz and 4400-5000MHz EVB

**Table 8.1 3300 – 3800MHz EVB @ $T_A=+25^{\circ}C$  Unless Otherwise Specified; Venable = High**

Parameter	Test Condition	Minimum	Typical	Maximum	Unit
Gain	3600MHz	16.5	17.5		dB
Noise Figure	3600MHz		0.4	0.5	dB
EVB Noise Figure	3600MHz		0.5	0.6	dB
Input Return Loss	3600MHz		14		dB
Output Return Loss	3600MHz		10		dB
OP1dB	3600MHz		19.5		dBm
OIP3	3600MHz, 0dBm per tone, Tone Spacing 1MHz	30	33		dBm
Switching Rise Time	10/90% of the RF value		300		nsec
Switching Fall Time	10/90% of the RF value		350		nsec

**Table 8.2 3700 – 4200MHz EVB @ $T_A=+25^{\circ}C$  Unless Otherwise Specified; Venable = High**

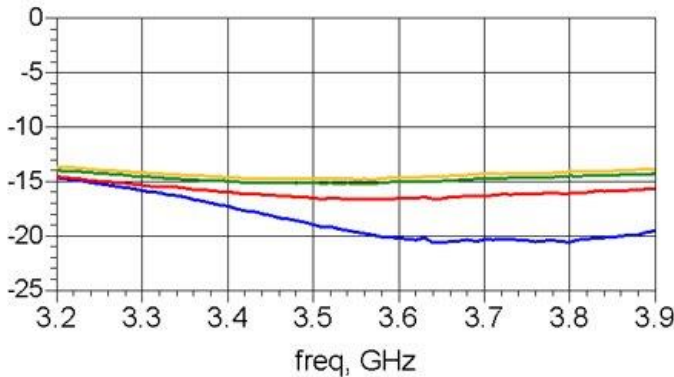
Parameter	Test Condition	Minimum	Typical	Maximum	Unit
Gain	Across Band		15.5-16.5		dB
Noise Figure	Across Band		0.5-0.6		dB
EVB Noise Figure	Across Band		0.6-0.7		dB
Input Return Loss	Across Band		8-12		dB
Output Return Loss	Across Band		8-12		dB
OP1dB	Across Band		19-20.5		dBm
OIP3	Across Band, 0dBm per tone, Tone Spacing 1MHz		33-34		dBm
Switching Rise Time	10/90% of the RF value		300		nsec
Switching Fall Time	10/90% of the RF value		350		nsec

**Table 8.3 4400 – 5000MHz EVB @T<sub>A</sub>=+25°C Unless Otherwise Specified; Venable = High**

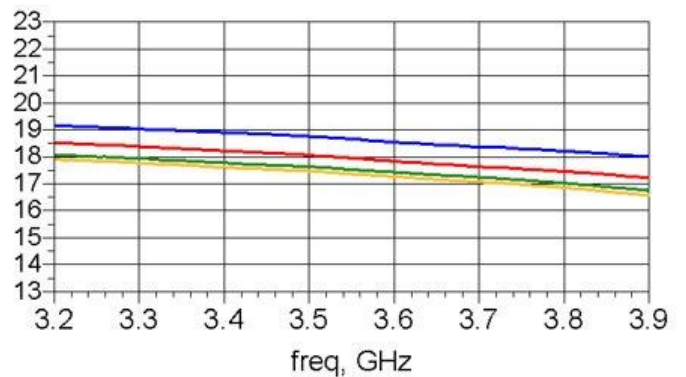
Parameter	Test Condition	Minimum	Typical	Maximum	Unit
Gain	Across Band		16		dB
Noise Figure	Across Band		0.55-0.65		dB
EVB Noise Figure	Across Band		0.7-0.8		dB
Input Return Loss	Across Band		10.4-12.4		dB
Output Return Loss	Across Band		7.5-9		dB
OP1dB	Across Band		18-20		dBm
OIP3	Across Band, 0dBm per tone, Tone Spacing 1MHz		33-36		dBm
Switching Rise Time	10/90% of the RF value		300		nsec
Switching Fall Time	10/90% of the RF value		350		nsec

**9.0 Typical Characteristics**

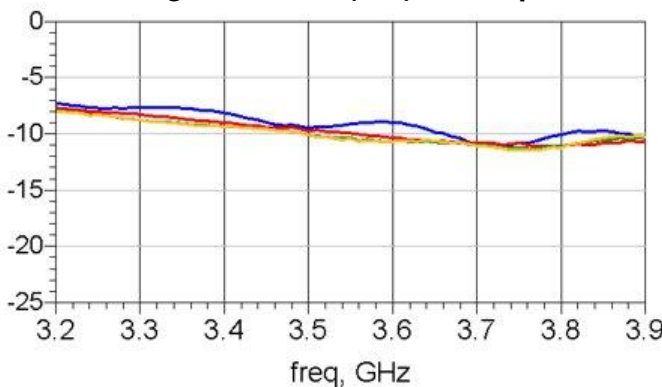
**9.1 3300 - 3800MHz tuned EVB (V<sub>dd</sub>=5V, I<sub>DQ</sub>=60mA), -40°C, 25°C, 85°C, 105 °C, Narrowband**



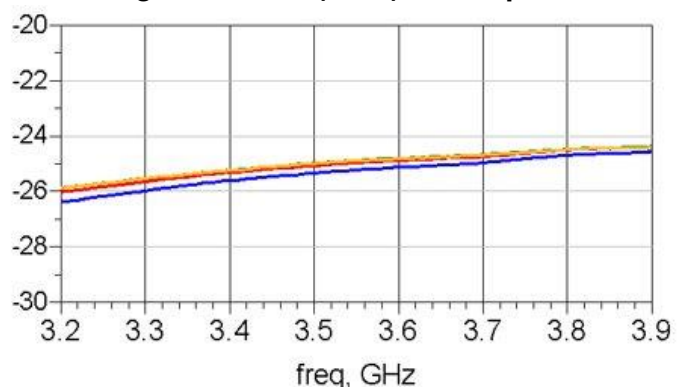
**Figure 9.1 S11 (IRL) vs Freq**



**Figure 9.2 S21 (Gain) vs Freq**

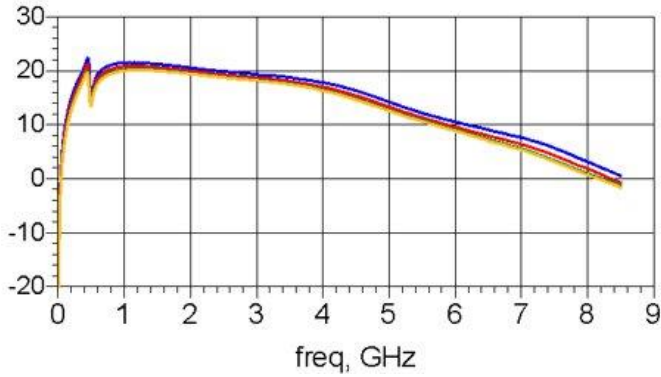


**Figure 9.3 S12 (Rev Iso) vs Freq**

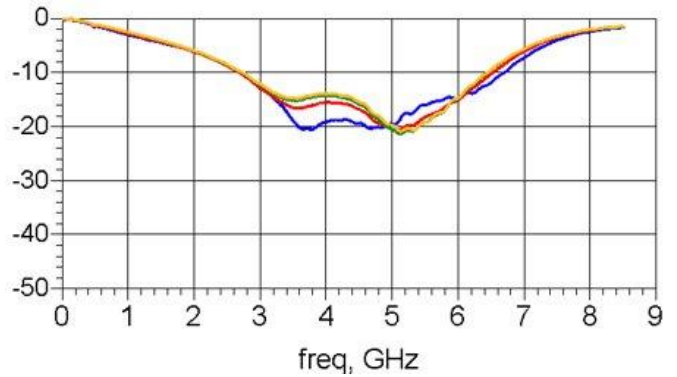


**Figure 9.4 S22 (ORL) vs Freq**

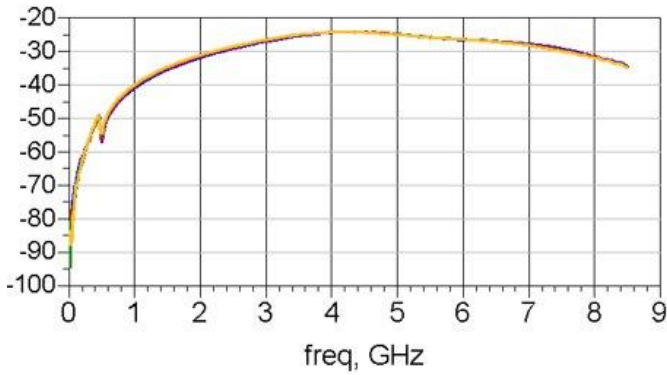
**9.2 3300 - 3800MHz tuned EVB (Vdd=5V, I<sub>DQ</sub>=60mA), -40°C, 25°C, 85°C, 105 °C, Broadband**



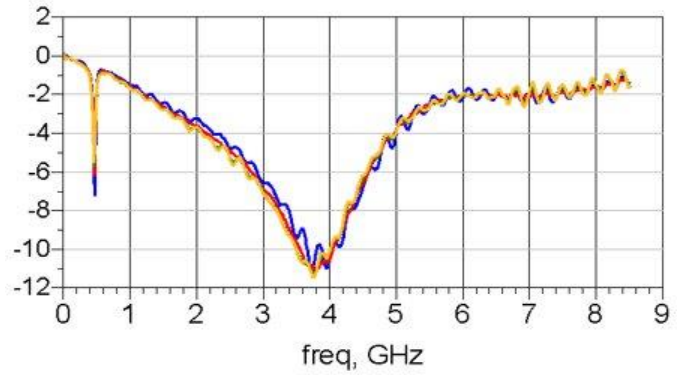
**Figure 9.5 S11 (IRL) vs Freq**



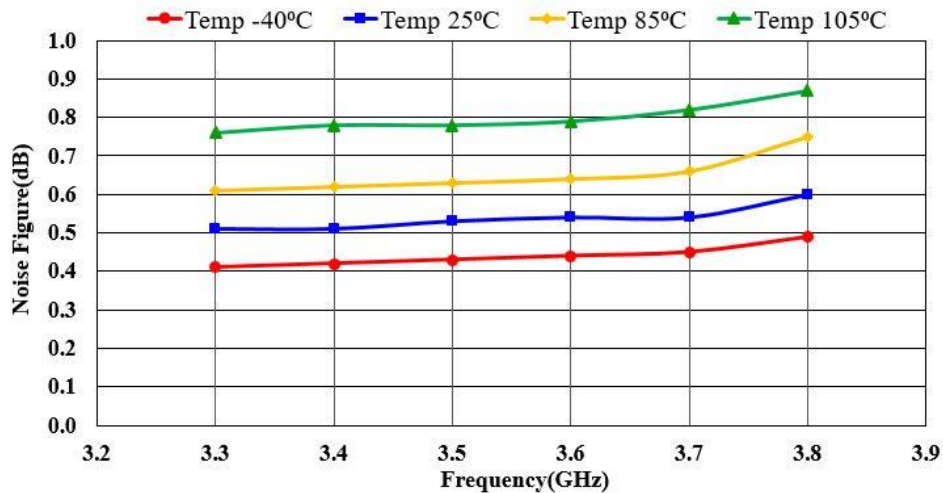
**Figure 9.6 S21 (Gain) vs Freq**



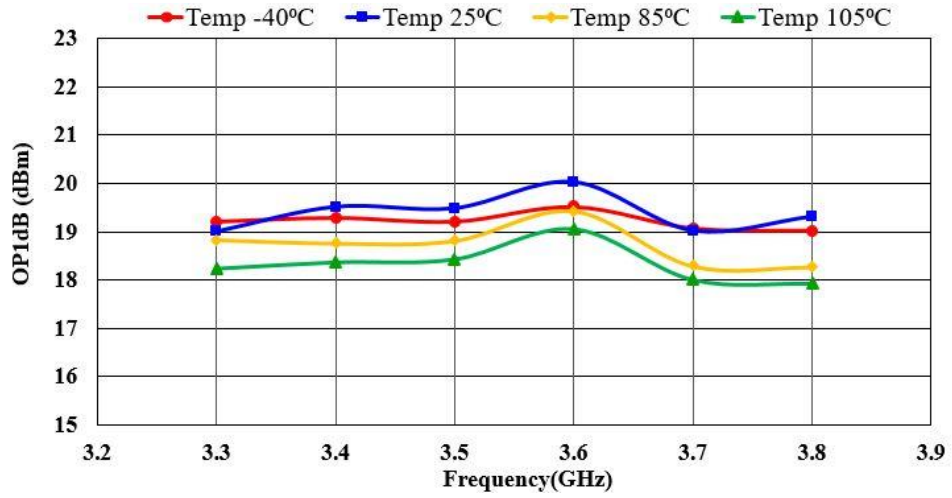
**Figure 9.7 S12 (Rev Iso) vs Freq**



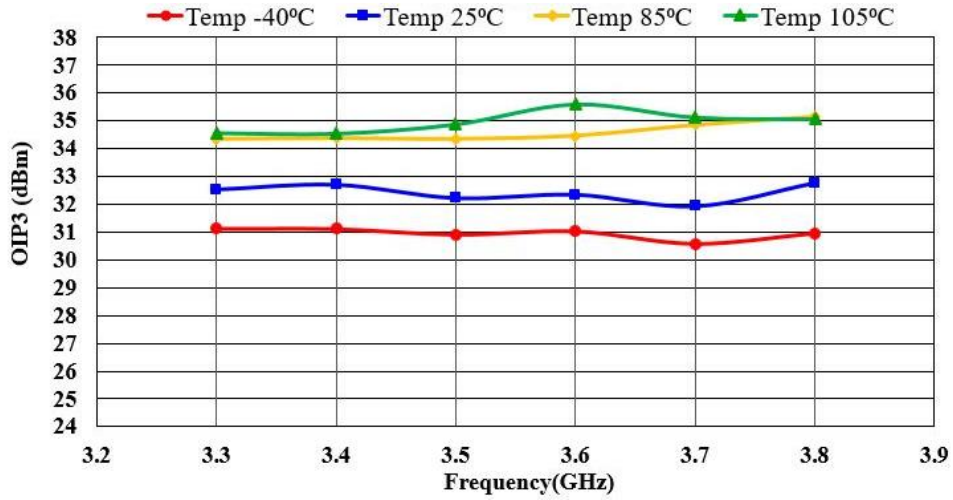
**Figure 9.8 S22 (ORL) vs Freq**



**Figure 9.9 Noise Figure (EVB) vs Freq**



**Figure 9.10 Output P1dB vs Freq**



**Figure 9.11 Output IP3 vs Freq**

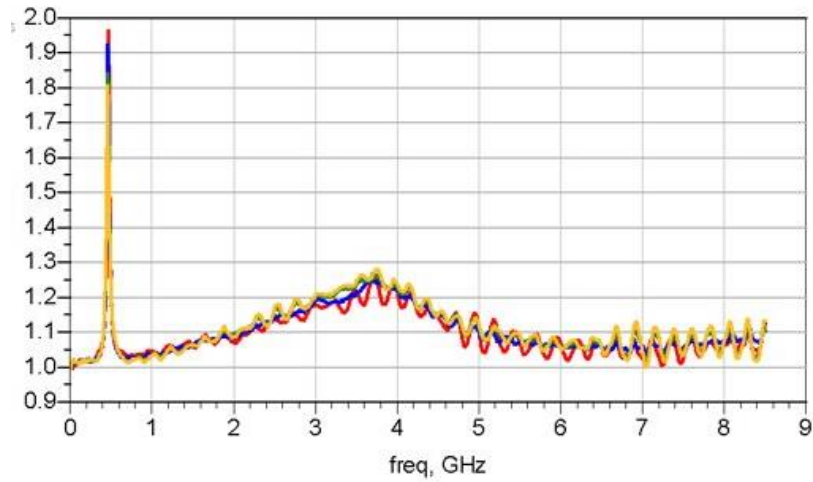


Figure 9.12 Mu1 vs Freq

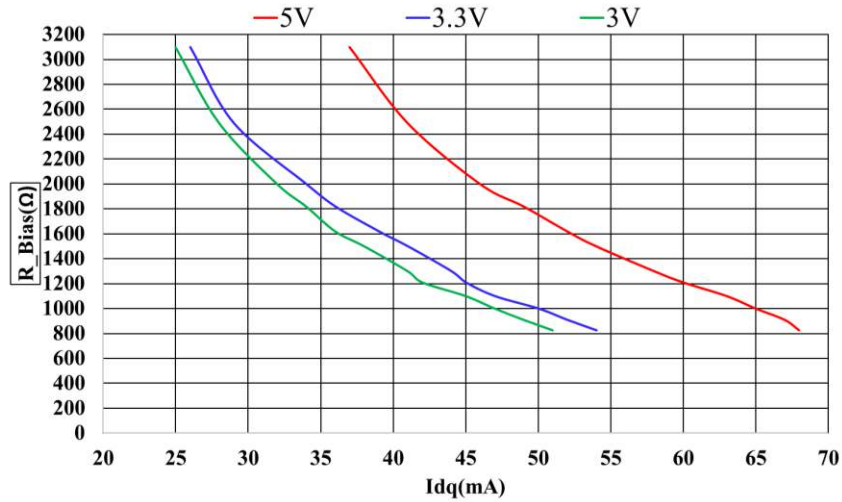
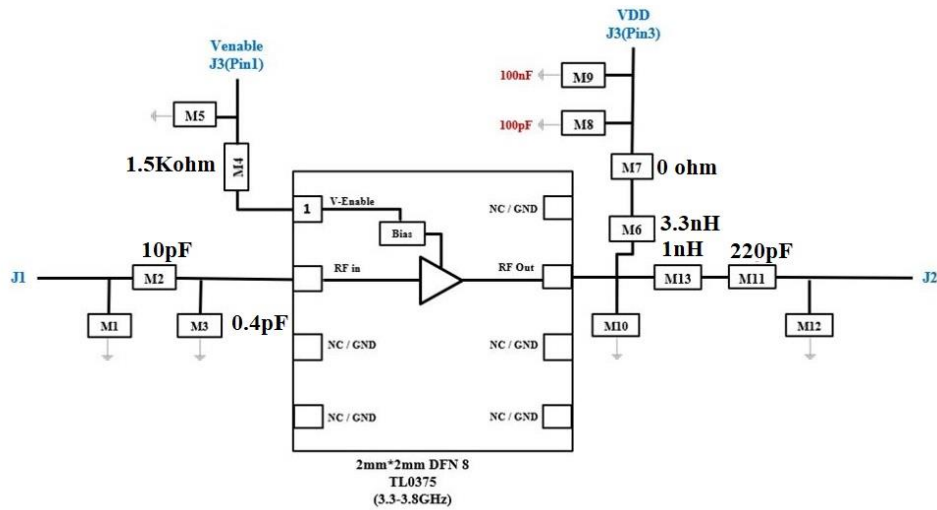


Figure 9.13 Rbias on Venable vs Idq

## 10.0 Evaluation Boards

### 10.1 3300 - 3800MHz EVB



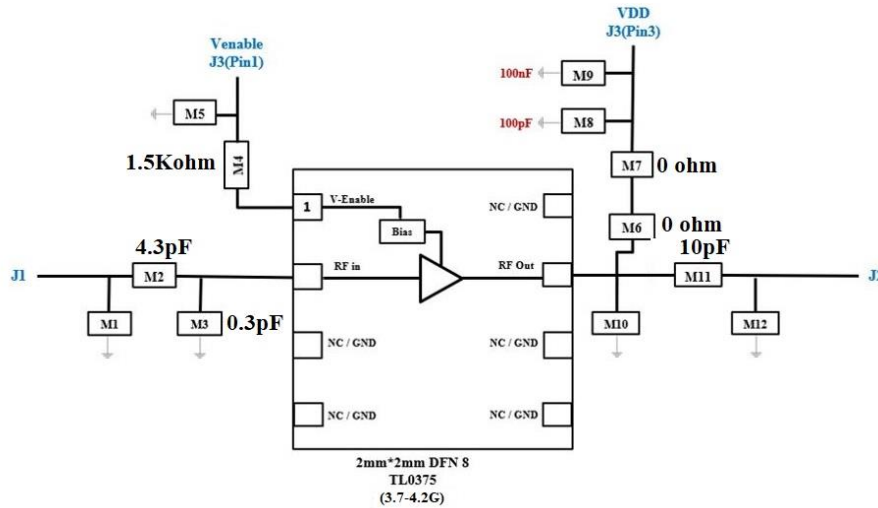
**Figure 10.1 Schematic of the 3300-3800MHz EVB**

**Table 10.1 BOM of the 3300-3800MHz EVB**

Component ID	Value	Manufacturer	Recommended Part Number
M2	10pF	Murata	GJM1555C1H100JB01
M3	0.4pF	Murata	GJM1555C1HR40BB01
M6	3.3nH	Coilcraft	0402HP-3N3XGE
M4	1.5KΩ	Panasonic	ERJ-2RKF1501X
M8	100pF	AVX	04025A101JAT4A
M9	100nF	TDK	C1005X7R1H104K050BE
M7	0Ω	Panasonic	ERJ-2GE0R00X
M11	220pF	Kemet	C0402C221K5GACAUTO
M13	1nH	Coilcraft	0402HP-1N0XJE
PCB	Rogers RO4350B, 20 mils, 1 oz copper		



**10.2 3700 - 4200MHz EVB**

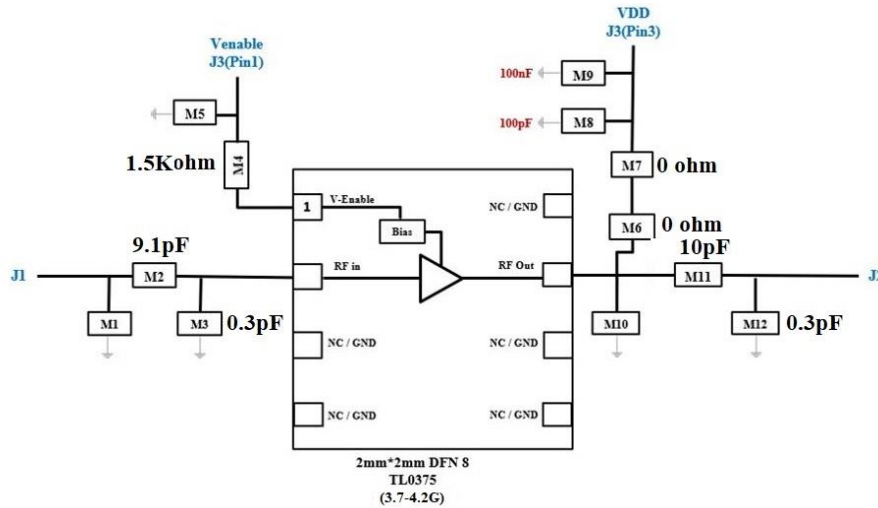


**Figure 10.2 Schematic of the 3700-4200MHz EVB**

**Table 10.2 BOM for 3700 - 4200MHz EVB**

Component ID	Value	Manufacturer	Recommended Part Number
M2	4.3pF	Murata	GJM1555C1H4R3BB01
M3	0.3pF	Murata	GJM1555C1HR30BB01
M4	1.5KΩ	Panasonic	ERJ-2RKF1501X
M8	100pF	AVX	04025A101JAT4A
M9	100nF	TDK	C1005X7R1H104K050BE
M7	0Ω	Panasonic	ERJ-2GE0R00X
M6	0Ω	Panasonic	ERJ-2GE0R00X
M11	10pF	AVX	04025A100JAT4A
PCB	Rogers RO4350B, 20 mils, 1 oz copper		

**10.3 4400-5000MHz EVB**

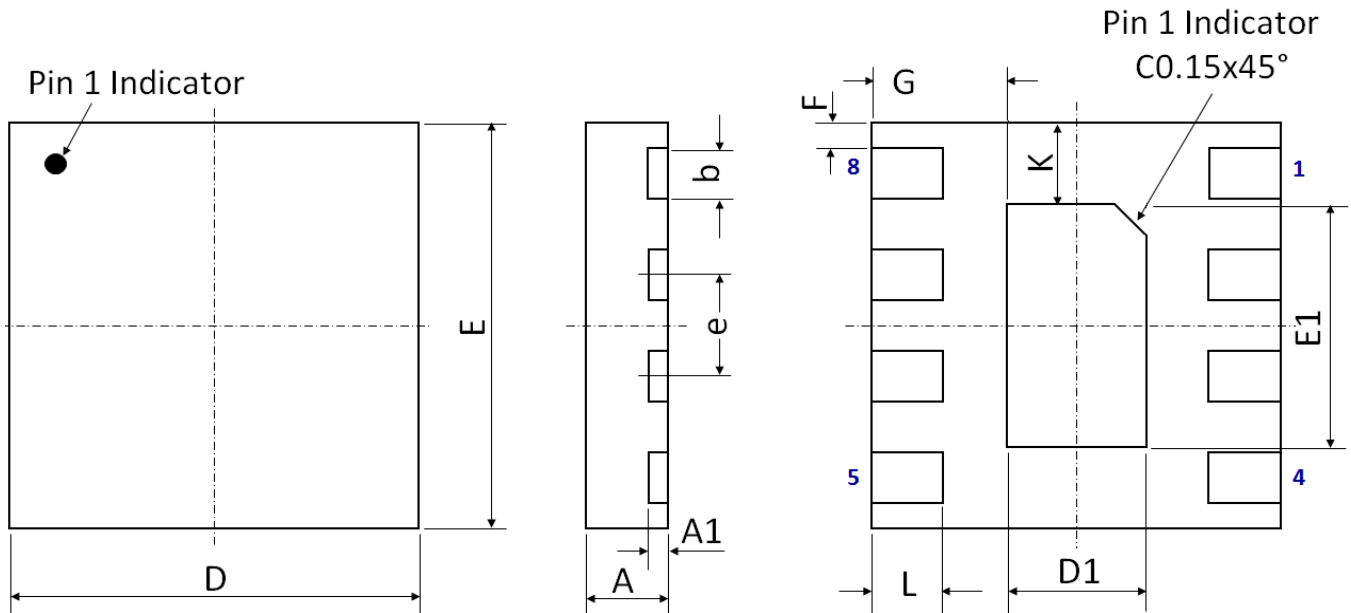


**Figure 10.3 Schematic of the 4400-5000MHz EVB**

**Table 10.3 BOM for 4400-5000MHz EVB**

Component ID	Value	Manufacturer	Recommended Part Number
M2	9.1pF	Murata	GJM1555C1H9R1BB01
M4	1.5KΩ	Panasonic	ERJ-2RKF1501X
M3	0.3pF	Murata	GJM1555C1HR30BB01
M8	100pF	AVX	04025A101JAT4A
M9	100nF	TDK	C1005X7R1H104K050BE
M7	0Ω	Panasonic	ERJ-2GE0R00X
M6	0Ω	Panasonic	ERJ-2GE0R00X
M11	10pF	AVX	04025A100JAT4A
M12	0.3pF	Murata	GJM1555C1HR30BB01
PCB	Rogers RO4350B, 20 mils, 1 oz copper		

**11.0 Device Package Information**



**Figure 11.1 Device Package Drawing**  
(All dimensions are in mm)

**Table 11.1 Device Package Dimensions**

Dimension (mm)	Value (mm)	Tolerance (mm)	Dimension (mm)	Value (mm)	Tolerance (mm)
A	0.75	$\pm 0.05$	E	2.00 BSC	$\pm 0.05$
A1	0.203	$\pm 0.02$	E1	1.20	$\pm 0.05$
b	0.25	$\pm 0.02$	F	0.125	$\pm 0.02$
D	2.00 BSC	$\pm 0.05$	G	0.66	$\pm 0.03$
D1	0.68	$\pm 0.03$	L	0.35	$\pm 0.05$
e	0.50 BSC	$\pm 0.05$	K	0.40	$\pm 0.05$

**Note:** Lead finish: Pure Sn without underlayer; Thickness:  $7.5\mu\text{m} \sim 20\mu\text{m}$  (Typical  $10\mu\text{m} \sim 12\mu\text{m}$ )

**Attention:**

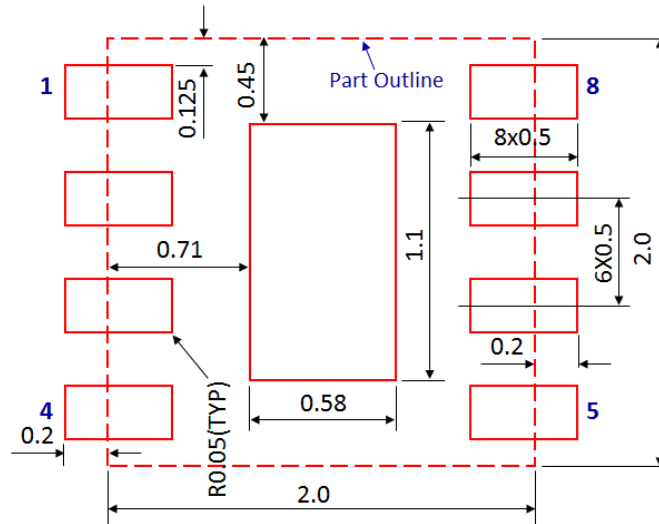
Please refer to application notes *TN-001* and *TN-002* at <http://www.tagoretech.com> for PCB and soldering related guidelines.



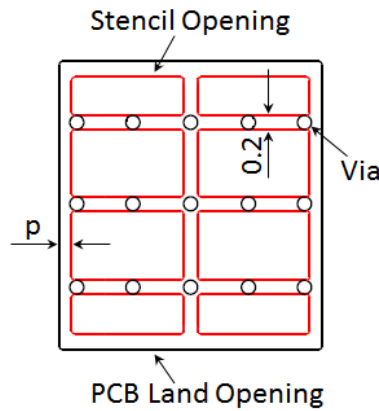
**13.0 PCB Stencil Design**

**Guidelines:**

- [1] Laser-cut, stainless steel stencil is recommended with electro-polished trapezoidal walls to improve the paste release.
- [2] Stencil thickness is recommended to be 125µm.



**Figure 13.1 Stencil Openings**  
(Dimensions are in mm)



**Figure 13.2 Stencil Openings Shall not Cover Via Areas If Possible**  
(Dimensions are in mm)



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